

FIG. 1

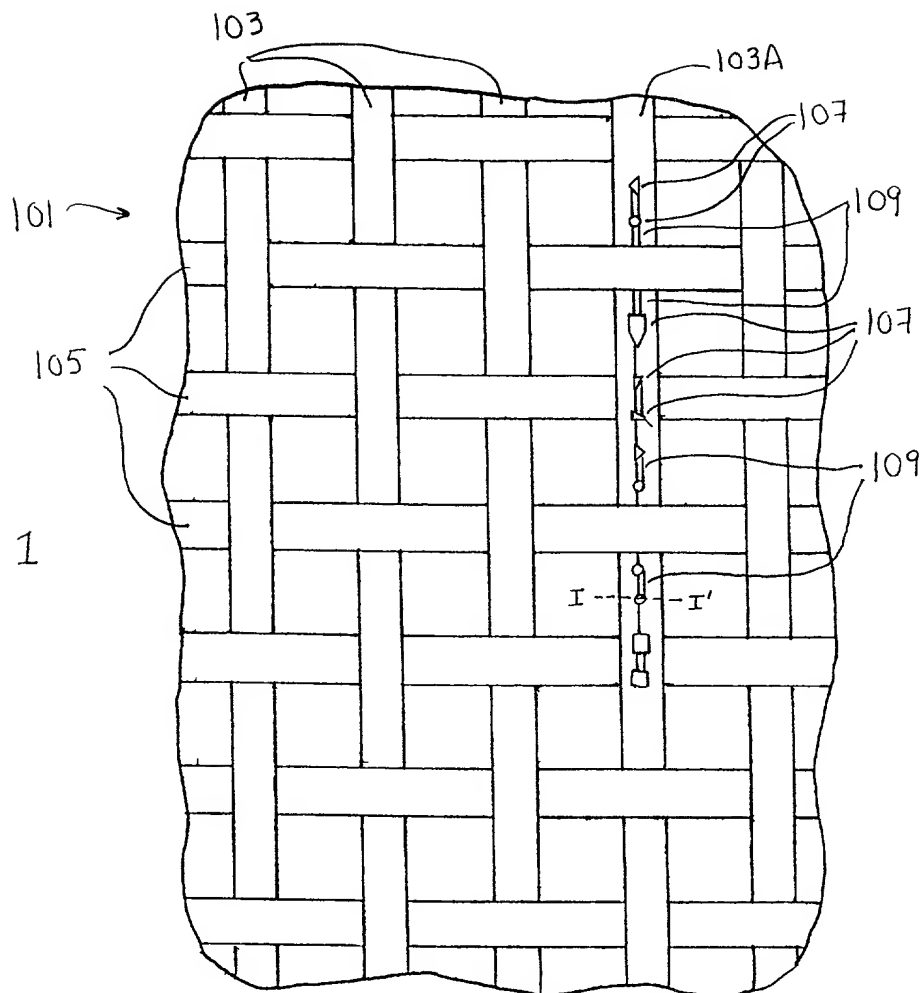
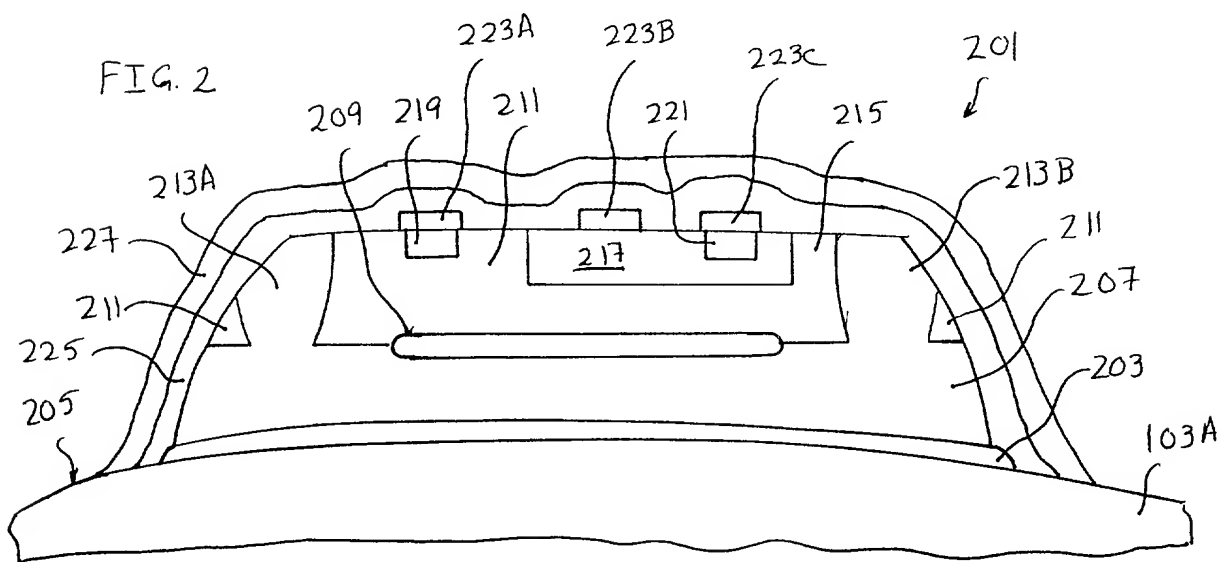


FIG. 2



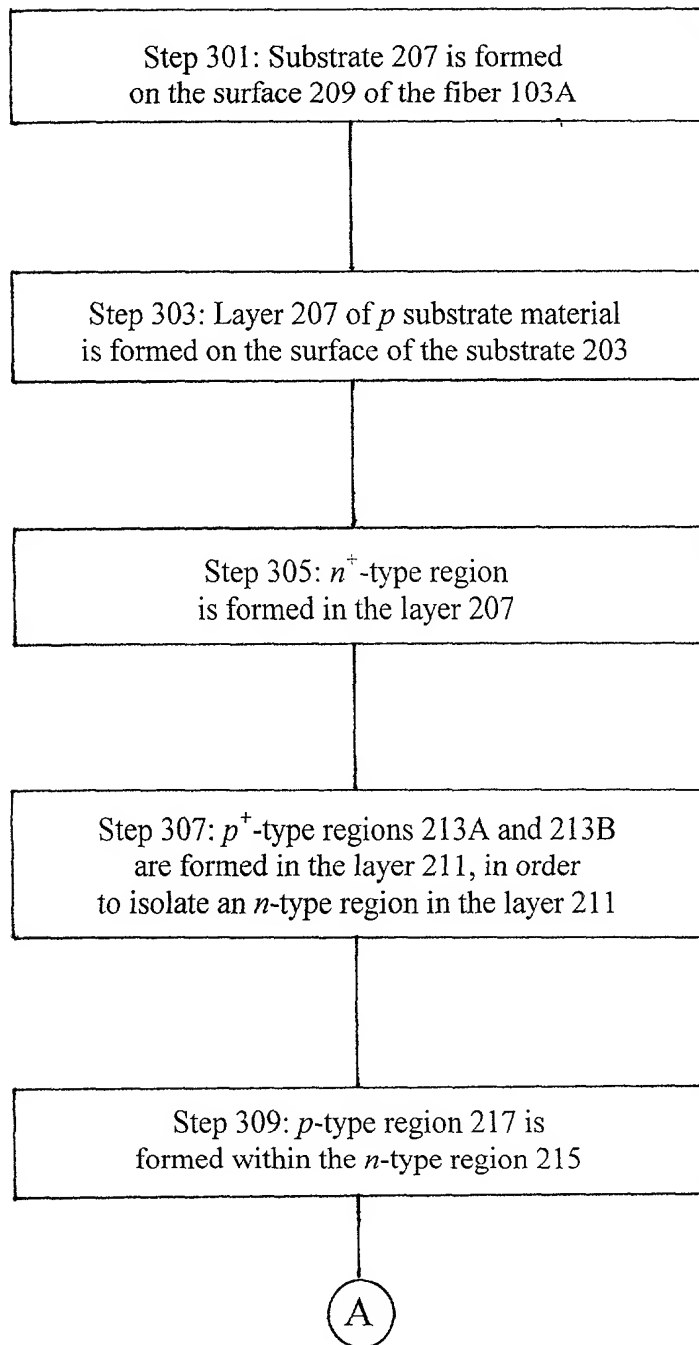


FIG. 3A

A

Step 311: n^+ -type region 219 is formed in n -type region 215 and an n^+ -type region 221 is formed in p -type region 217

Step 313: Electrodes 223A, 223B and 223C are formed

Step 315: Protective layer 225 is formed over the transistor 201

Step 317: Transistor 201 is covered with a shielding layer 227

FIG. 3B

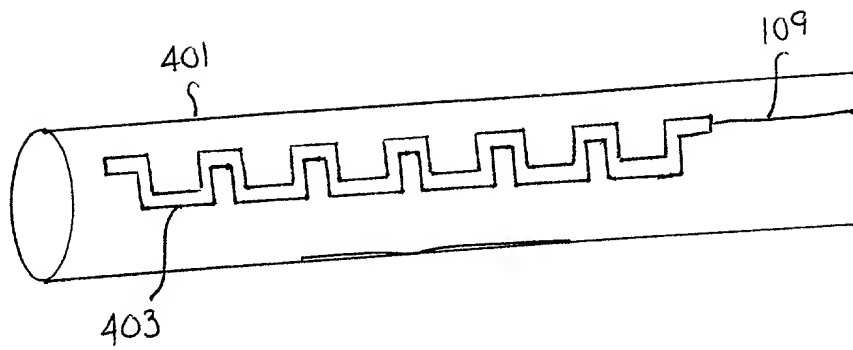


FIG. 4

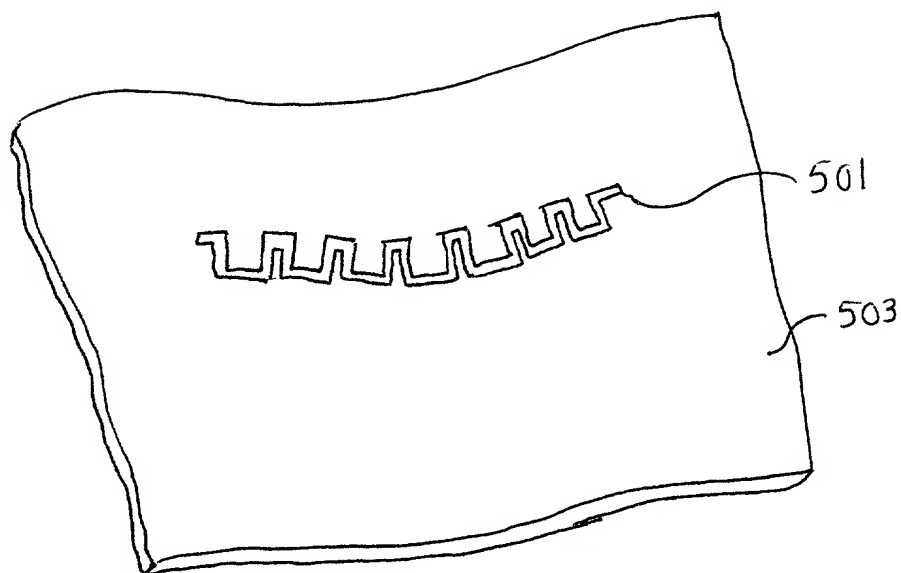


FIG. 5